

Office of NUCLEAR ENERGY



Advanced Sensors and Instrumentation

Thermometry CT-24IN070205 3:00PM – 3:20PM EST Wednesday, Nov 6th, 2024

Advanced Sensors and Instrumentation (ASI) Annual Program Webinar November 4, 6-7, 2024

PI: Richard Skifton, PhD; Co-PI: Brian Jaques, PhD

Idaho National Laboratory/Boise State University

Project Overview

Nuclear Thermocouple Technology:

- Complete characterization of advanced insulation materials for use in advanced nuclear sensors for high temperature applications – This task focuses on the development of high temperature (> 2000 °C) insultation materials for nuclear instrumentation (e.g., thermocouple, ultrasound thermometry, SPND, etc.). The main need is the manufacturability and/or advance manufacturing capabilities in such non-oxide materials as aluminum nitride (AIN), silicon carbide (SiC), and others, for example. The high temperature materials allow for sensors to reach higher temperatures themselves without adding drift or impurities to the signal. The main tests will be performed on thermocouples, but the advanced insulations apply to other sensors, as well.
- In FY24 R&D activities were carried out in the following technical areas:
 - M3CT-24IN0702051-(Carryover) Journal article with HTIR-TC testing results using the different heat treatment methods
 - M3CT-24IN0702052-Characterization of insulation materials for use in advanced nuclear sensors for high temperature applications

Personnel:

- PI: Richard Skifton, PhD, Idaho National Laboratory
- CO-PI: Brian Jaques, PhD, Boise State University

Project Overview

Schedule:

		2024											
Milestone / Activity	STI	Oct	Nov	Dec	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep
M3CT-24IN0702051-(Carryover) Journal article with HTIR-TC testing results using the different heat treatment methods	Yes	M3											
M3CT-24IN0702052- Characterization of insulation materials for use in advanced nuclear sensors for high temperature applications	Yes												M3

Technology Impact

- Next generation reactors are pushing temperatures higher than ever (> 1600 °C)
- This merits the increase in material capabilities, namely, ceramic insulators that hold most high temperature sensors in their designed position
- This work applies to thermocouples, SPNDs, ultrasound thermometry, and others



Traditional Thermocouple Insulators

Ceramic Insulator	Interaction with Niobium Onset Temperature	Interaction with Molybdenum Onset Temperature	Melting point	
	(°C)	(°C)	(°C)	
HfO ₂	1300	Not observed	2758	
AI_2O_3	1450	Not observed	2072	
BeO	1600	Not observed	2578	
MgO	1800	Not observed	2852	
ThO ₂	1800	Not observed	3390	
ZrO ₂	-	-	2715	





• The electrical resistivity of alumina limits operation of the HTIR-TCs above 1600 °C.

Alternative High Temperature Ceramic Insulators



 ZrC, ZrN, and B₄C were not considered further due to their low electrical resistivity in comparison to alumina.

Alternative Thermocouple Insulators

Ceramic Insulator	Interaction with Niobium Onset Temperature	Interaction with Molybdenum Onset Temperature	Melting point	
	(°C)	(°C)	(°C)	
Nitride				
Si ₃ N ₄	Not observed	1000	1900	
AIN	1400	Not observed	2200	
H-BN	1700	1700	2973	
Carbides				
SiC	1300	1500	2730	
B ₄ C	Not observed	1100	2350	





Diffusion Couple Set up



C)



1 cm





• Samples were cross-section after heat treatment and prepared for SEM characterization.

Chemical Stability – Niobium with Aluminum Nitride at 1700 °C





50 µm



N Kα1,2

ΑΙ Κα1



50 µm

During heat treatment at 1700 °C for 6 hrs aluminum diffused throughout the bulk of the niobium foil.

Chemical Stability – Niobium with Aluminum Nitride at 1700 °C



Chemical Stability – Niobium with Silicon Carbide at 1700 °C



Chemical Stability – Niobium with Silicon Carbide at 2000 °C



 During heat treatment at 2000 °C for 6 hrs the niobium appeared to form a eutectic phase with the SiC.

Chemical Stability – Niobium with Silicon Carbide at 2000 °C

Electron Image 3



100µm

Nb La1



100µm

C Kα1,2



Si Kα1



During heat treatment at
2000 °C for 6 hrs the
niobium was wetted to the
surface of the SiC but
there is a lack of a
diffusion region forming.

Chemical Stability – Niobium with H-BN at 1700 °C



50µm

Chemical Stability – Niobium with ZrO₂ at 1700 °C



200 µm



Nb La1



Zr La1

- During removal of the ZrO₂/Nb/ZrO₂ diffusion couple from the graphite fixture the ZrO₂ fractured and crumbled into pieces.
- During heat treatment at 1700 °C for 6 hrs an interaction region formed between the ZrO₂ and the niobium foil.



50µm

Digital Light Processing printing of ZrO₂ (Surrogate Ceramic)



• Sintering of the as printed ZrO₂ resulted in a high density phase pure ZrO₂.

Optimization of Printed ZrO₂ Porosity



The sintering profile was adjusted to increase the porosity of the ZrO₂, and in doing so produce a crushable part.

Concluding Remarks

The stability of alternative high-temperature ceramic insulators was conducted with HTIR-TC relevant materials. The down selection of AIN, SiC, ZrO₂, and H-BN was made based upon thermodynamic predictions, electrical resistivity and thermal conductivity at elevated temperatures, and empirically determined chemical stability with niobium and molybdenum.

- The interaction with surrogate Nb and Mo was shown
- The printing of relevant ceramics in advanced sensor geometries was trialed
- Additionally, powder packing of relevant ceramic powders was verified



• Patent application from current work:

My Completed Records							
IDR #	Docket #	Title	Accepted				
13485	BA-1609	Particulate insulation packing and wire alignment for sensors using acoustic nodal points	6/5/2024				

• Journal submissions are forthcoming from the current work

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Thank You

